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The Low-Frequency Character of the Thermal Correction to the Casimir Force between Metallic Films
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J.R. Torgerson and S.K. Lamoreaux
University of California,Los Alamos National Laboratory,
Physics Division P-23, M.S. H803, Los Alamos, NM 87545
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The frequency spectrum of the finite temperature correction to the Casimir force can be determined by use of the Lifshitz formalism for metallic plates of finite conductivity. We show that the correction for the TE electromagnetic modes is dominated by frequencies so low that the plates cannot be modelled as ideal dielectrics. We also address issues relating to the behavior of electromagnetic fields at the surfaces and within metallic conductors, and calculate the surface modes using appropriate low-frequency metallic boundary conditions. Our result brings the thermal correction into agreement with experimental results that were previously obtained.

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I. INTRODUCTION

A recent paper [1], in which simultaneous consideration of the thermal and finite conductivity corrections to the Casimir force between metal plates leads to a significant deviation from an experimental result [2] and previous theoretical work, has attracted considerable interest. The principal conclusion in [1] leading to this discrepancy is that the TE electromagnetic mode (**E** parallel to the surface) does not contribute to the force at finite temperature. Arguments against the analysis given in [1] have been numerous [3, 4, 5, 6] but not universally accepted [7, 8].

A careful numerical analysis of the problem leads us and others to conclude that the results presented in [1] are mathematically correct. As we show here, this analysis does not accurately represent the experimental arrangement used in [2]. The aspect of the problem that has not been considered in detail is the appropriateness of a dielectric model of the metallic plates at low frequencies, which, as we will show, are most relevant for the thermal correction. The purpose of this note is to expand on our previous work [9] and to point out that the proper boundary conditions for conductors have not yet been directly applied to this problem, and to show that the experimental result [2] can be fully explained by this application.

II. SPECTRUM OF THE TE MODE THERMAL CORRECTION OF THE CASIMIR FORCE

Following Ford [10], the spectrum of the Casimir force is given by Eqs. (2.3) and (2.4) of Lifshitz' seminal paper [11]. We note that

$$\frac{1}{2}\coth\frac{\hbar\omega}{2kT}=\frac{1}{2}+\frac{1}{\exp(\hbar\omega/kT)-1}=\frac{1}{2}+g(\omega) \quad (1)$$

and we only include the second term on the right-hand side in the determination of the spectrum of the thermal correction. From Eq. (2.4) of [11], the spectrum of the TE mode excitation between parallel plates can be described by

$$\left[\frac{\hbar}{\pi^2c^3}\right]F_\omega = \left[\frac{\hbar}{\pi^2c^3}\right]\omega^3 g(\omega) \times \ \mathrm{Re}\int_C p^2dp\left[\frac{(s+p)^2}{(s-p)^2}e^{-2ip\omega a/c}-1\right]^{-1} \quad (2)$$

$$s=\sqrt{\epsilon(\omega)-1+p^2} \quad (3)$$

where a is the plate separation, and we have assumed that the plates are made of the same material with vacuum between them. The integration path C can be separated into C_1 for $p=1$ to 0, which describes the effect of plane waves, and C_2 with pure imaginary values $p=i0$ to $i\infty$ for exponentially damped (evanescent) waves.

In anticipation that the effect is a low-frequency phenomenon, we use the parameters for Au in [1] for Im $\epsilon=\epsilon_2$ and employ the Kramers-Kronig relations to determine Re $\epsilon=\epsilon_1$. We find for frequencies $\omega<10^{14}$ s^{-1} that, to good approximation,

$$\epsilon_1=\frac{-1.48\times10^4}{1+(\omega/\omega_0)^2};\quad \epsilon_2=\frac{1.8\times10^{18}}{\omega(1+(\omega/\omega_0)^2)} \quad (4)$$

with $\omega_0=3.3\times10^{13}$ s^{-1}.

In [1], a net deviation from the zero-temperature value of the Casimir force is predicted to be about 25% for a plate separation of 1 μm at 300 K. The experimental results reported in [2] had their greatest sensitivity around 1 μm, and disagree significantly with the results in [1]. As a comparison, we numerically integrate Eq. 2) for $a=1$ μm and $T=300$ K, using Eq. (4) for the permittivity. The results are shown in Fig. 1, where we have separated the results from the two integration paths. In Fig. 1a, it can be seen that there is no significant deviation from the perfectly conducting case. On the other hand, the contribution from evanescent waves, shown in Fig. 1b, is large and the integrated value is in good agreement with the result given in [1].

We see immediately that the main contributions of the TE-mode finite conductivity correction are around $\omega = 10^{10} - 10^{13}$ s^{-1}. This behavior is due to an approximately quadratic increase with ω of the C_2 integral and a suppression beginning at $\omega = kT/\hbar = 4 \times 10^{13}$ s^{-1} due to $g(\omega)$. This is a low frequency range and we can question certain assumptions in [1] and in the Lifshitz calculation, among others, in regard to theoretical predictions relevant to the experimental arrangement in [2].

III. LOW FREQUENCY LIMIT AND FIELD BEHAVIOR IN METALLIC MATERIALS

When the depth of penetration of the electromagnetic field into a metal,

$$\delta = c/\sqrt{2\pi\mu\sigma\omega} \tag{5}$$

where σ is the conductivity and μ is the permeability (for Au and Cu, $\sigma \approx 3 \times 10^{17}$ s^{-1}, $\mu = 1$), becomes of the same order as the mean free path of the conduction electrons, it is no longer possible to describe the field in terms of a dielectric permeability [12, 13]. This occurs for optical frequencies $\omega \approx 5 \times 10^{13}$ s^{-1} for metals such as Au and Cu where the mean free path, at 300 K, is about 3×10^{-6} cm [14] (p. 259). At frequencies above 10^{14} s^{-1} the permeability description again becomes valid because on absorbing a photon, a conduction electron acquires a large kinetic energy and has a shortened mean free path. However, in the interaction of a field with a material surface, **E** and **H** can always be related linearly through the surface impedance (which relates the electric field at the surface to a surface current hence magnetic field); this approach has been used in calculation of the Casimir force [15]. A related correction arises from the the plasmon interaction with the surface which becomes significant near the plasma frequency of the metal, and has been estimated as nearly 10% [16] for sub-μm plate separations.

The proper boundary conditions for a conducting plane have been discussed by Boyer [17]. He points out that when (using here the notation of [1]) $\omega \ll \eta^2\rho/4\pi$, where ρ is the resistivity and η is the dissipation, the usual dielectric boundary conditions are not applicable. For Au, using the parameters in [1], this limit is met for $\omega \ll 4 \times 10^{14}$ s^{-1}. This corresponds to an optical wavelength of 5 μm, which implies that for plate separations significantly larger than this, and of course for $\omega \to 0$, the plates must be treated as good conductors.

The boundary conditions for a conducting surface are discussed in [18] (Sec. 8.1). At low frequencies (e.g., where the displacement current can be neglected), a tangential electric field at the surface of a conductor will induce a current $\mathbf{j}_\parallel = \sigma\mathbf{E}_\parallel$, where σ is the conductivity. The presence of the surface current leads to a discontinuity in the normal derivative of $\mathbf{H}_\parallel$, hence a discontinuity in the normal derivative of $\mathbf{E}_\parallel$, at the boundary of a conducting surface. These boundary conditions are quite different from the dielectric case where the fields and their derivatives are assumed continuous.

IV. ELECTROMAGNETIC MODES BETWEEN METALLIC PLATES

We are interested in modes between two conducting plates separated by a distance a. In the limit that the plates are thin films of thickness $d > \delta$, the skin depth, we can assume that the plates are infinitely thick and the problem is considerably simplified. This is well-satisfied for the conditions of the experiment [2] when $\omega > 10^{11}$ s^{-1} in which case $\delta < 0.7$ μm compared to the film thickness of 1 μm. Essentially all of the TE mode thermal correction comes in the 10^{11} and 10^{13} s^{-1} range as shown in Fig. 1.

Taking the $\hat{z}$ axis as perpendicular to the plates, and the mode propagation direction along $\hat{x}$, for the case of TE modes (also referred to as H or magnetic modes), $E_x = 0$. The plates surfaces are located at $z = 0$ and $z = a$. For a perfect conductor, $\partial H_z/\partial z = 0$ at the conducting surfaces. A finite conductivity makes this derivative non-zero, and can be estimated from the small electric field E_y that exists at the surface of the plate, (see [18], Sec. 8.1 and Eq. (8.6))

$$\vec{E}_\parallel = \hat{y}E_y = \sqrt{\frac{\omega}{8\pi\sigma}}(1-i)\hat{n}\times\vec{H}_\parallel. \tag{6}$$

where $\vec{H}\| = \hat{x}H_x$ and it is assumed that the displacement current in the metal plate can be neglected ($\sigma >> \omega$), and that the inverse of the mode wavenumber is less than δ. E_y and H_x are related through Maxwell's equation $\vec{\nabla}\times\vec{H} = \partial\vec{E}/c\partial t$. Assuming a time dependence of $e^{-i\omega t}$, and vacuum between the plates,

$$\frac{\partial H_x}{\partial z} = \pm\frac{i\omega}{c}E_y. \tag{7}$$

where $\pm$ indicates sign of $\hat{n}$ at $z = 0$ and $z = a$ respectively. The boundary conditions at the surfaces are thus

$$\frac{\partial}{\partial z}H_z = \pm i\sqrt{\frac{\omega}{8\pi\sigma}}\left(\frac{\omega}{c}\right)(1-i)H_z \equiv \pm\alpha H_z. \tag{8}$$

Solutions of the form $H_\parallel(z) = Ae^{Kz} + Be^{-Kz}$, where $K^2 = k^2 - \omega^2/c^2$ and k is the transverse wavenumber, can be constructed for the space between the conducting plates. The eigenvalues K can be determined by the requirement that Eq. (7) be satisfied at $z = 0$ and $z = a$. With the usual substitution $\omega = i\xi$, the eigenvalues K are then given by (see [19], Sec. 7.2)

$$G_{TE}(\xi) \equiv \frac{(\alpha+K)^2}{(\alpha-K)^2}e^{2Ka} - 1 = 0 \tag{9}$$

and the force can be calculated by the techniques outlined in [19], Sec. 7.3.

This result can be recast in the notation of the Lifshitz formalism, and the spectrum of the thermal correction can be calculated as before. Noting that $K = i\omega p/c$,

$$F_\omega = \omega^3 g(\omega) \int_C p^2 dp \left[\frac{(\alpha + i\omega p/c)^2}{(\alpha - i\omega p/c)^2} e^{-2i\omega p/c} - 1 \right]^{-1}. \tag{10}$$

Results of a numerical integration are shown in Fig. 2, where it can be seen by comparison with Fig. 1 that the metallic plate boundary condition does not show a significant contribution from the C_2 integral of the TE mode thermal correction and is therefore similar to that for the "perfect conductor" boundary condition. This reconciles the discrepancy between the prediction in [1] and the experimental results reported in [2].

V. CONCLUSION

The problem of calculating the TE mode contribution to the Casimir force has been previously treated with the "Schwinger prescription" [20] of setting the dielectric constant to infinity before setting $\omega = 0$. This prescription has become controversial [21], a term that can be used to describe the entire history of the theory of the temperature correction. However, there is no doubt that the issues brought up in [1] are important.

The purpose of our calculation is to take a different approach and to study the low-frequency behavior of the correction in order to understand its character. We have shown that the finite temperature correction in [1] is a low-frequency phenomenon. The frequency is sufficiently low so that treating the plates as bulk dielectrics is not valid. By use of a more realistic description of the field interaction with the plates we show that the modes between metallic plates of finite conductivity produce a finite temperature correction in close agreement with the perfectly conducting case. The principal difference between our result and the previous work is that we have allowed for the possibility that the derivatives of the fields at the conducting boundary are discontinuous. This possibility exists because the fields produce currents in the conducting plates that are discontinuous across the boundary between the vacuum and the conductor. Although it is tempting to model the finite conductivity as a modification to the dielectric permittivity, such a model fails when the mean free path of the conduction electrons exceeds the penetration depth of the electromagnetic field, and thus fails for frequencies of interest for the thermal correction to the TE electromagnetic mode.

We have shown that the conducting boundary conditions that are applicable for frequencies where the TE mode thermal correction has its significant contribution lead to a net increase of the TE mode force, and is of the same magnitude as the perfectly conducting case. This result is in agreement with the experimental results reported in [2]. However, additional and improved experiments with large plate separations (greater than 2 μm) with both conducting and dielectric plates would provide the definitive test. A particularly tempting dielectric would be diamond which offers both theoretical and experimental benefits.

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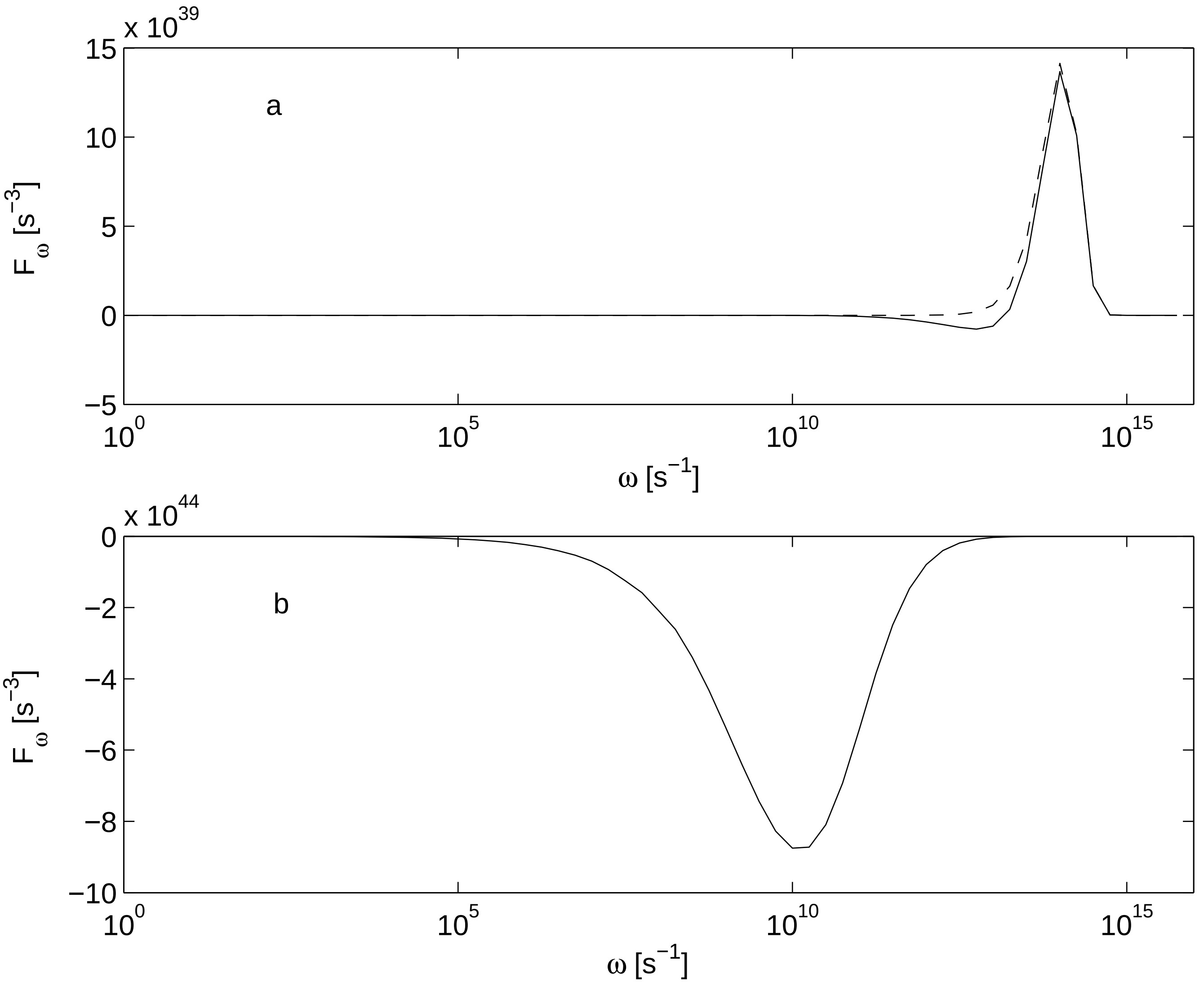

FIG. 1: The net finite-temperature contribution to the Casimir force is determined by $F = (\hbar/\pi c^3)\int_0^\infty F_\omega d\omega$ and is attractive when $F > 0$. a: The two curves represent the C_1 path for perfectly conducting plates (dashed curve) and for plates with permittivity given by Eq. (4)(solid curve). The net force force for the latter is 0.95 times the perfectly conducting case. b: For a perfect conductor, the C_2 integral is zero. The net contribution from the C_2 path is -169 times the perfectly conducting contribution from the C_1 path, and its addition to the TE mode zero-point contribution reduces the net TE mode force to nearly zero, which is the result obtained in [1]. All are for $a = 1$ μm, $T = 300$ K.

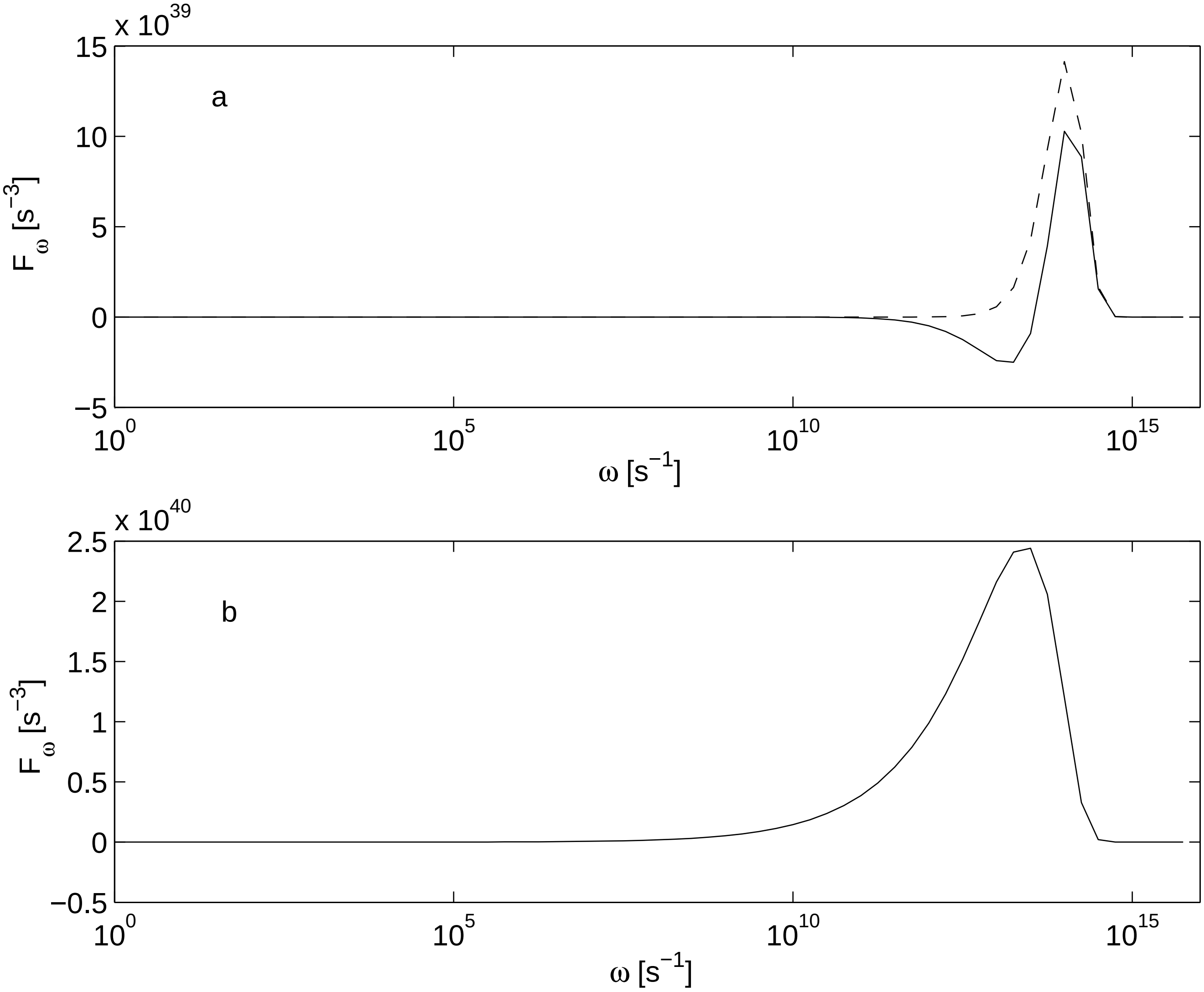

FIG. 2: Numerical results for F_ω using the finite conductivity boundary conditions. The integrated force for the C_2 path contribution is 1.47 times greater than the C_1 integration, and the total net force for both paths is 1.75 times greater than the perfectly conducting case. Treatment of the plates as conducting metals fails above $\omega = 10^{14}$ s^{-1}. All are for $a = 1$ μm, $T = 300$ K.